

| L Number | Hits | Search Text | DB | Time stamp |
|----------|--------|---|---|------------------|
| 1 | 4263 | 438/201,211,216,241,257,258,260-266,591,593.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:09 |
| 2 | 5167 | 257/239,261,298,315-326.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:09 |
| 3 | 8777 | 438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:10 |
| 4 | 625 | (438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.) and ((first adj gate) with (second adj gate) with substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:24 |
| 5 | 555 | ((438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.) and ((first adj gate) with (second adj gate) with substrate)) and (dop\$4 diffus\$3) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:11 |
| 6 | 42 | ((438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.) and ((first adj gate) with (second adj gate) with substrate)) and (dop\$4 diffus\$3)) and ((first adj (insulat\$3 dielectric) adj (film layer)) with (nitrogen (silicon adj nitride))) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:17 |
| 7 | 6 | ((438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.) and ((first adj gate) with (second adj gate) with substrate)) and (dop\$4 diffus\$3)) and ((first adj (insulat\$3 dielectric) adj (film layer)) with nitrogen) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:21 |
| 8 | 4 | ((438/201,211,216,241,257,258,260-266,591,593.ccls. or 257/239,261,298,315-326.ccls.) and ((first adj gate) with (second adj gate) with substrate)) and (dop\$4 diffus\$3)) and ((first adj (insulat\$3 dielectric) adj (film layer)) with hydrogen) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:25 |
| 9 | 395882 | 438/\$.ccls. 257/\$.ccls. 365/\$.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:24 |
| 10 | 2402 | (438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and ((first adj gate) with (second adj gate) with substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:30 |
| 11 | 12 | ((438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and ((first adj gate) with (second adj gate) with substrate)) and ((first adj (insulat\$3 dielectric) adj (film layer)) with hydrogen) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:29 |
| 12 | 515 | (438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and ((first adj (insulat\$3 dielectric) adj (film layer)) with (nitrogen hydrogen)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:39 |

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|----|----|---|---|------------------|
| 13 | 32 | ((438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and ((first adj (insulat\$3 dielectric) adj (film layer)) with (nitrogen hydrogen))) and ((first adj gate) with (second adj gate) with substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:31 |
| 14 | 9 | (438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and ((first adj (insulat\$3 dielectric) adj (film layer)) with (embed\$4 near2 between) with gate\$1) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:41 |
| 15 | 42 | (438/\$.ccls. 257/\$.ccls. 365/\$.ccls.) and (((insulat\$3 dielectric) adj (film layer)) with (embed\$4 near2 between) with gate\$1) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:57 |
| 16 | 17 | ("5338700" "5374580" "5401681" "5604147" "5789304" "5824582" "5998257" "6001685" "6020234" "6023084" "6046093" "6077742" "6080620" "6100129" "6110774" "6221711" "6232176").PN. | USPAT | 2004/04/28 10:48 |
| 17 | 61 | (((insulat\$3 dielectric) adj (film layer)) with (embed\$4 near2 between) with gate\$1) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/04/28 10:57 |